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Ph.D. in Theoretical Chemistry, 1954, University of Pavia, Italy. Did postdoctoral work on electrical properties of organic polymers at the Polytechnical Institute of Milan. Worked on singlet-triplet transitions of organic molecules with Professor Michael Kasha at Florida State University for two years. Subsequently, was a postdoctoral fellow for the Atomic Energy Commission with Professor K. S. Pitzer at the University of California, Berkeley, where his work was in the species of carbon vapors. Following this, he was a postdoctoral fellow at the University of Chicago with Professor R. S. Mulliken. His work there consisted of Hartree-Fock computations on diatomic and linear molecules. Presently he is the group leader of the Theoretical Chemistry and Physics group of the IBM Research Laboratory in San Jose, where he is working on Hartree-Fock correlation, and relativistic computations for atoms and molecules.

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Erratum:

D. P. Seraphim, A. E. Brennemann, F. M. d'Heurle and H. L. Friedman, *IBM Journal* 8, 400-409 (September, 1964). In Fig. 7b, p. 408, the vertical scale of the upper chart should be 0.5mA/div instead of 1.0 mA/div. Figure 7a is correct as shown.



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